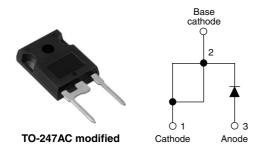
COMPLIANT



Vishay High Power Products

High Performance Schottky Generation 5.0, 30 A



PRODUCT SUMMARY	<i>f</i>
IE(A)()	30 A

 V_R

 V_F at 30 A at 125 $^{\circ} C$

100 V

0.64 V

FEATURES

- 175 °C high performance Schottky diode
- Very low forward voltage drop
- Extremely low reverse leakage
- Optimized V_F vs. I_R trade off for high efficiency
- · Increased ruggedness for reverse avalanche capability
- RBSOA available
- · Negligible switching losses
- Submicron trench technology
- Full lead (Pb)-free and RoHS compliant devices
- Designed and qualified for industrial level

APPLICATIONS

- High efficiency SMPS
- Automotive
- High frequency switching
- · Output rectification
- · Reverse battery protection
- Freewheeling
- · Dc-to-dc systems
- · Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL CHARACTERISTICS VALUES UNITS							
V _{RRM}		100	· ·				
V _F	30 Apk, T _J = 125 °C (typical)	V					
T _J	Range	- 55 to 175	°C				

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	30PT100	UNITS
Maximum DC reverse voltage	V _R	T _J = 25 °C	100	V

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _C = 156 °C, r	50 % duty cycle at T _C = 156 °C, rectangular waveform			
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load	2200	Α	
non-repetitive surge current	I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	450		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 30 mH		135	mJ	
Repetitive avalanche current	I _{AR}	Limited by frequency of operation and time pulse duration so that $T_J < T_J$ max. I_{AS} at T_J max. as a function of time pulse See fig. 8		I _{AS} at T _J max.	Α	

Document Number: 94532 Revision: 24-Jul-08

30PT100

Vishay High Power Products

____ VISHAY.

High Performance Schottky Generation 5.0, 30 A

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TYP.	MAX.	UNITS		
		30 A	T _ 25 °C	-	0.77		
Forward voltage drop	V _{FM} ⁽¹⁾	60 A	T _J = 25 °C	-	0.9	v	
Forward voltage drop	V FM (1)	30 A		-	0.64		
		60 A	T _J = 125 °C	-	0.76		
Reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	-	200	μΑ	
neverse leakage current	'RM \''	T _J = 125 °C	v _R = nateu v _R	TBD	15	mA	
Junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz) 25 °C		1650	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body		7.5	-	nΗ	
Maximum voltage rate of change	dV/dt	Rated V _R		=	10 000	V/µs	

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature rar	nge	T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resist junction to case	ance,	R _{thJC}	DC operation	0.8	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.25	· C/VV
Annyovimata waight				6	g
Approximate weight				0.21	OZ.
minim				6 (5)	kgf · cm
Mounting torque -	maximum			12 (10)	(lbf \cdot in)
Marking device			Case style TO-247AC modified (JEDEC)	30PT100	

For technical questions, contact: diodes-tech@vishay.com

Document Number: 94532
Revision: 24-Jul-08



High Performance Vishay High Power Products Schottky Generation 5.0, 30 A

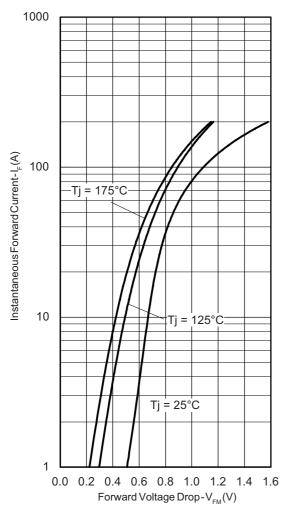


Fig. 1 - Maximum Forward Voltage Drop Characteristics

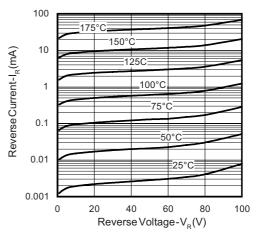


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

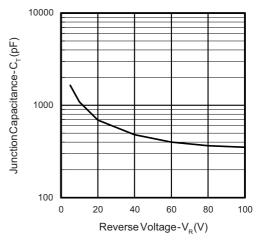


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

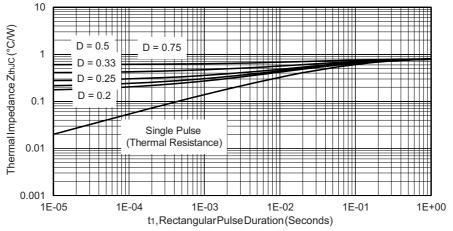


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Vishay High Power Products

High Performance Schottky Generation 5.0, 30 A



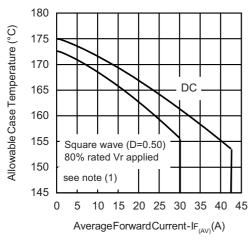


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

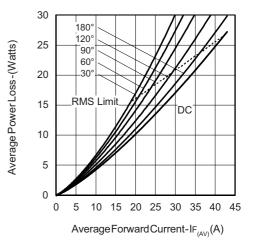


Fig. 6 - Forward Power Loss Characteristics

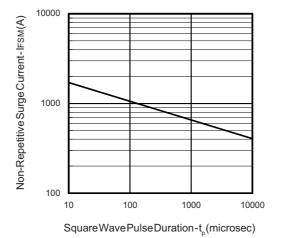


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

 $\begin{array}{l} \text{(1) Formula used: } T_C = T_J - (Pd + Pd_{REV}) \; x \; R_{thJC}; \\ Pd = Forward \; power \; loss = I_{F(AV)} \; x \; V_{FM} \; at \; (I_{F(AV)}/D) \; (see \; fig. \; 6); \\ Pd_{REV} = Inverse \; power \; loss = V_{R1} \; x \; I_R \; (1 - D); \; I_R \; at \; V_{R1} = 80 \; \% \; rated \; V_R \\ \end{array}$

Document Number: 94532 Revision: 24-Jul-08



High Performance Vishay High Power Products Schottky Generation 5.0, 30 A

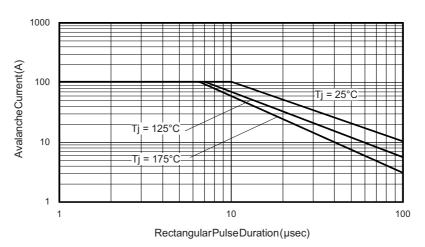


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

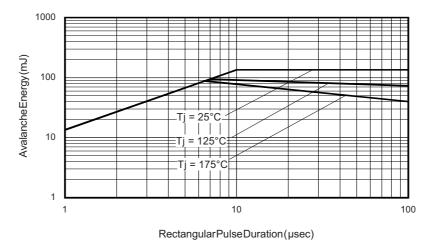


Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)

30PT100

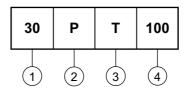
Vishay High Power Products

High Performance Schottky Generation 5.0, 30 A



ORDERING INFORMATION TABLE

Device code



1 - Current rating (30 A)

2 - Package:

P = TO-247 (modified)

3 - T = Trench

4 - Voltage code (100 V)

Tube standard pack quantity: 25 pieces

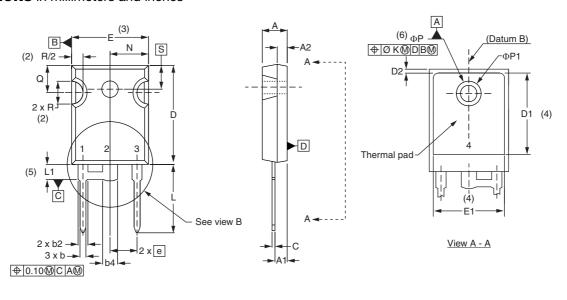
LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95253				
Part marking information	http://www.vishay.com/doc?95255			
SPICE model	http://www.vishay.com/doc?95232			

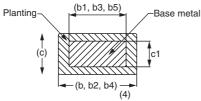
Document Number: 94532 Revision: 24-Jul-08

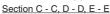


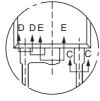
Vishay Semiconductors

DIMENSIONS in millimeters and inches









View B

<u>Lead assignments</u> <u>Diodes</u>

- 1. Anode/open
- 2. Cathode 3. - Anode

SYMBOL	MILLIN	IETERS	INC	INCHES	
STWIDGE	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.37	0.065	0.094	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.86	0.015	0.034	
c1	0.38	0.76	0.015	0.030	
D	19.71	20.70	0.776	0.815	3

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.72	-	0.540	-	
е	5.46	BSC	0.215	BSC	
ΦК	2.	54	0.0	10	
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
N	7.62	BSC	0.	.3	
ΦР	3.56	3.66	0.14	0.144	
ФР1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	1.78	0.216	
S	5.51	BSC	0.217	BSC	

Notes

D1

- (1) Dimensioning and tolerance per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) ΦP to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC outline TO-247 with exception of dimension c

0.515

Legal Disclaimer Notice



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Revision: 11-Mar-11